MAX.

800E

800F

800

12

95

UNIT

V

А

А

### Three quadrant triacs guaranteed commutation

# BTA212B series D, E and F

MAX.

600D

600E

600F

600

12

95

### **GENERAL DESCRIPTION**

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The 'sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

### PINNING - SOT404

main terminal 1

main terminal 2

main terminal 2

PIN

1

2

3

mb

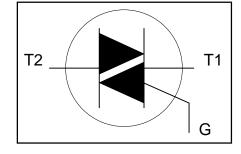
# DESCRIPTION

### SYMBOL

**BTA212B-**

**BTA212B-**

**BTA212B-**



### LIMITING VALUES

gate

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V <sub>drm</sub>	Repetitive peak off-state voltages		-	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{mb} \le 99 \degree C$	- [	12	2	A
I <sub>TSM</sub>	Non-repetitive peak on-state current	full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$ $t = 16.7 \ ms$	-	95 109		AA
l²t dl <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after triggering	t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	45	5	A <sup>2</sup> s A/μs
I <sub>GM</sub> V <sub>GM</sub> P <sub>GM</sub>	Peak gate current Peak gate voltage Peak gate power		-	2 5 5		A V W
P <sub>G(AV)</sub>	Average gate power	over any 20 ms period	-	0.5	5	W
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature		-40 -	150 125		Ĵ, Ĵ,

QUICK REFERENCE DATA

PARAMETER

voltages

current

mb

**PIN CONFIGURATION** 

₽

2

3

1

Repetitive peak off-state

Non-repetitive peak on-state

RMŠ on-state current

SYMBOL

 $V_{DRM}$ 

T(RMS)

 $I_{TSM}$ 

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/us.

### BTA212B series D, E and F

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	- -	- - 55	1.5 2.0 -	K/W K/W K/W

### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
		BTA212B-		D	D	E	F	
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ T2+G+	-	1.0	5	10	25	mĄ
   IL	Latching current	T2+ G- T2- G- V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A	-	2.2 3.3	5 5 5	10 10	25 25	mA mA
'L		T2+ G+ T2+ G- T2- G-	- - -	6 6 9	15 25 25	25 30 30	30 40 40	mA mA mA
I <sub>H</sub>	Holding current	V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A	-	3.8	15	25	30	mA
					D, E, F	=		
$V_{T} V_{GT}$	On-state voltage Gate trigger voltage	$I_T = 17 \text{ A}$ $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$	- - 0.25	1.3 0.7 0.4		1.6 1.5 -		V V V
I <sub>D</sub>	Off-state leakage current	$T_{j} = 125 °C$ $V_{D} = V_{DRM(max)}$ ; $T_{j} = 125 °C$	-	0.1		0.5		mA

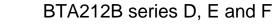
### **DYNAMIC CHARACTERISTICS**

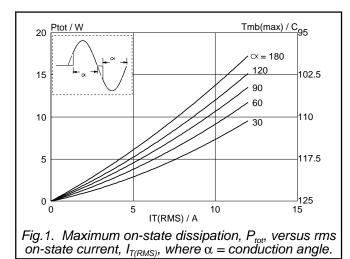
 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
		BTA212B-	D	E	F	D		
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110$ °C; exponential waveform; gate open circuit	20	60	70	30	-	V/µs
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20V/\mu \text{s}; \text{ gate}$ open circuit	1.8	3.5	5	3	-	A/ms
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 0.1 \text{ V}/\mu\text{s}; \text{ gate}$ open circuit	5	16	19	100	-	A/ms
			D, E, F					
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu s$	-	-	-	2	-	μs

**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

# Three quadrant triacs guaranteed commutation





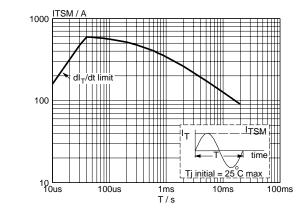
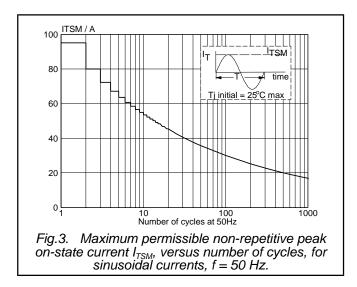
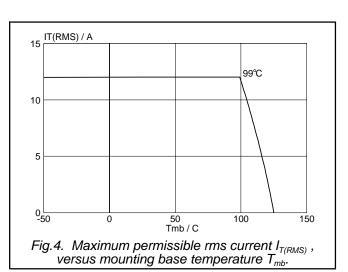


Fig.2. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20ms$ .





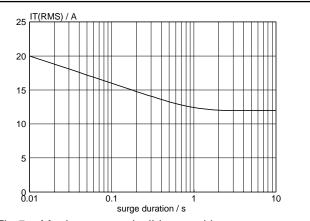
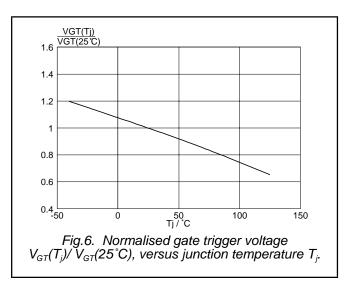
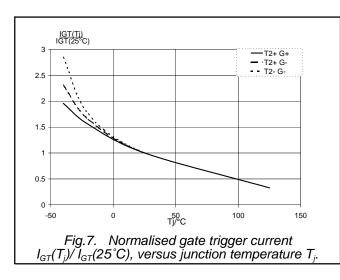


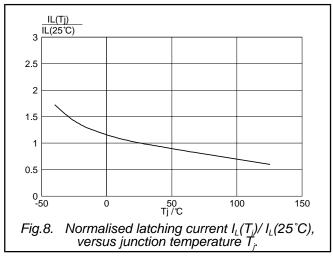
Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 99^{\circ}C$ .

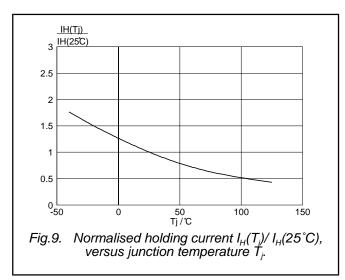


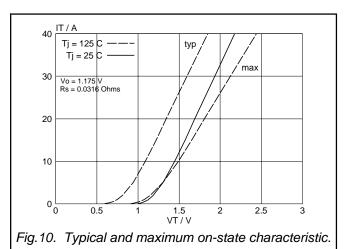
# Three quadrant triacs guaranteed commutation

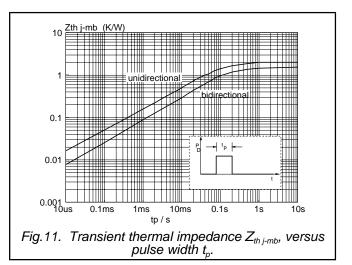
## BTA212B series D, E and F

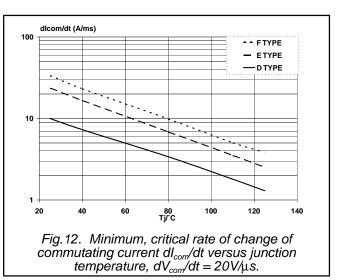








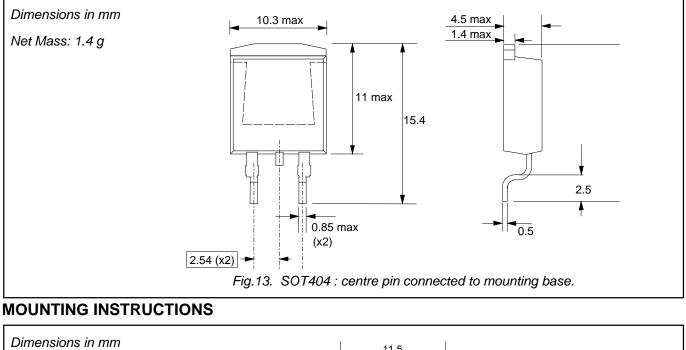


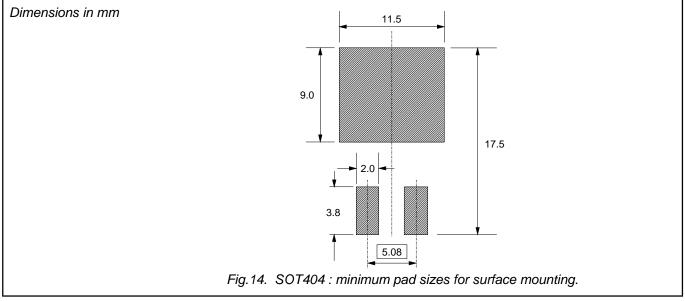


# Three quadrant triacs guaranteed commutation

# BTA212B series D, E and F

### **MECHANICAL DATA**





#### Notes

1. Plastic meets UL94 V0 at 1/8".

### Three quadrant triacs guaranteed commutation

### BTA212B series D, E and F

### DEFINITIONS

Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information					
Where application information is given, it is advisory and does not form part of the specification.					
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